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# Uniform core–shell Cu<sub>6</sub>Sn<sub>5</sub>@C nanospheres with controllable synthesis and excellent lithium storage performances†

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Metallic tin (Sn) is one of the most promising alternatives to graphite anodes for lithium ion batteries due to its higher theoretical capacity, higher packing density and safer thermodynamic potential, while the huge volume transformation during repeated cycling leads to rapid pulverization and consequently poor capacity retention. This work provides an easy-to-control method to prepare uniform core–shell Cu<sub>6</sub>Sn<sub>5</sub>@C nanospheres in which Cu<sub>6</sub>Sn cores (40–50 nm in diameter) are well encapsulated by PANI-derived carbon layers with a thickness of ~5 nm. The obtained Cu<sub>6</sub>Sn<sub>5</sub>@C exhibits an excellent cycling ability and good rate capabilities. Both the reversible capacity (518 mA h g<sup>−1</sup>) after 100 cycles and the initial coulombic efficiency (89.2%) are the highest values in Cu<sub>6</sub>Sn<sub>5</sub>-based materials. The impressive cycling performance is believed to result from the carbon coating that not only prevents particle agglomeration during the synthesis but also accommodates the vast structural transformation of the Cu<sub>6</sub>Sn<sub>5</sub> nanocores during the electrochemical (de)lithiation process, so ensuring good ionic and electronic transport to the core. The effect of synthesis conditions on the composition are also investigated systematically.

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## 1. Introduction

Low volumetric capacity and safety issues limit the performances of graphite-based anodes in high energy/power applications, such as electric vehicles (EVs) and hybrid electric vehicles (HEVs).<sup>1–4</sup> Metallic tin (Sn) is one of the most promising alternatives to graphite due to its high theoretical capacity (990 mA h g<sup>−1</sup>, 7200 mA h cm<sup>−3</sup>) (*cf.* graphite: 372 mA h g<sup>−1</sup>, 800 mA h cm<sup>−3</sup>), high packing density, and safe thermodynamic potential.<sup>5–8</sup> However, the large specific volume change that occurs during charging and discharging leads to rapid pulverization of the Sn electrode and consequently a decrease of electrical conductivity, resulting in poor capacity retention upon extended cycling.<sup>9</sup>

In order to overcome this problem, an effective approach is to alloy Sn with inactive metals such as Fe,<sup>10,11</sup> Co,<sup>12–17</sup> Cu,<sup>18–21</sup> Ni,<sup>22–25</sup> and Zn<sup>26,27</sup> that do not react as readily with lithium and thus provide a buffer matrix that can absorb the extensive volume expansion and contraction of Sn. In this respect, many efforts have focused on Sn–Cu alloys, which react with lithium at a few hundred milli-volts above the potential of metallic lithium and lithiated graphite electrodes Li<sub>x</sub>C<sub>6</sub> (*x* ≤ 1).<sup>28–30</sup> One of key issues in the synthesis of Cu–Sn alloys is to ensure intimate contact between Sn and Cu and at the same time inhibit the agglomeration of products due to the melting of Sn (and alloying with Cu) during heat treatment.

Ideally, the alloy should be synthesized in a nanostructured form to enhance electronic conduction and shorten the Li-ion migration paths.<sup>31</sup> Various methods including high energy ball milling,<sup>32</sup> direct melting,<sup>33</sup> electro-deposition,<sup>34,35</sup> and carbothermal reduction<sup>36</sup> have been used to prepare such Cu–Sn materials. However, it is difficult to prepare small/isolated particles with controlled size and morphology using these synthetic methods. Further, these relatively complicated synthesis routes are often not convenient for scaled-up production. Thus the efficiency of such approaches has been relatively limited. In recent years, electro-less deposition has been used to prepare Sn thin films on Cu substrates, with annealing leading to the formation of Cu–Sn thin film anodes.<sup>37,38</sup> The advantage of this method is that an intimate

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contact between Sn and Cu can be achieved, regardless of the shape of the Cu substrate.

It is believed that carbon surface modification presents significant advantages to enhance the cycleability of active materials, as it can prevent the aggregation of active particles, accommodate the strain of volume change, and enhance the surface electronic conductivity of such materials.<sup>39,40</sup> For example, Wang *et al.* found that polyamine (PANI) coating FePO<sub>4</sub> as opposed to the final LiFePO<sub>4</sub> product could effectively restrict the particle growth during the reaction of FePO<sub>4</sub> and CH<sub>3</sub>COOLi to form LiFePO<sub>4</sub>. PANI decomposed into carbon over the course of the reaction.<sup>41</sup> The resultant LiFePO<sub>4</sub> nanoparticles are coated with conductive carbon nanolayers and exhibits close-to-theoretical capacity and much improved rate capabilities.<sup>42</sup> This indicates that an intermediate coating can effectively control the size of final particles and in the process form a protective conducting shell around the particle. Similarly, pomegranate-like Sn@C,<sup>43</sup> Si@C,<sup>44,45</sup> Sb@C,<sup>46</sup> and Fe<sub>3</sub>O<sub>4</sub>@C<sup>47</sup> hierarchical nanocomposites are also reported recently and exhibited extraordinary performance for Li/Na storage.

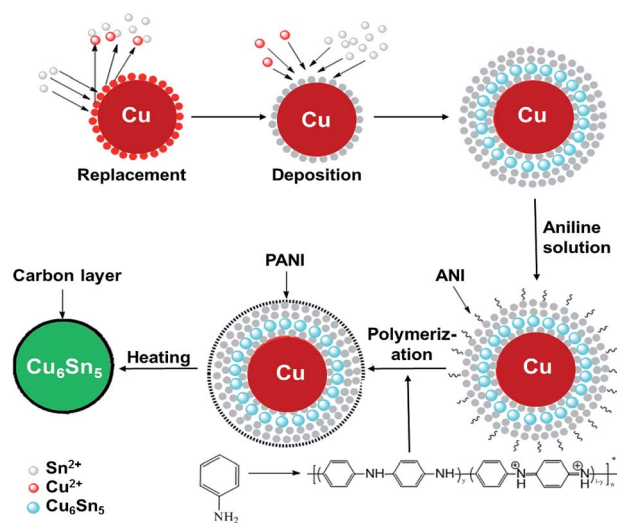
Motivated by the above findings, herein we propose a new strategy to prepare uniform core-shell Cu<sub>6</sub>Sn<sub>5</sub>@C nanospheres. Our strategy involves the electro-less preparation of Cu-Sn powder and the formation of double-shelled Cu@Sn@PANI intermediate compounds by fabricating Sn and PANI double layers around Cu nanoparticles, followed by an annealing step to generate core-shell Cu<sub>6</sub>Sn<sub>5</sub>@C nanospheres. The role of PANI is thus not only to act as the carbon source, but also to suppress the particle aggregation by isolating the Cu@Sn@PANI intermediate particles, ensuring that there is no growth beyond the nanoscale at each step. Hence, we were able to control fully the synthesis of high quality core-shell Cu<sub>6</sub>Sn<sub>5</sub>@C nanospheres at the nanoscale level. The Cu<sub>6</sub>Sn<sub>5</sub>@C nanospheres were electrochemically tested as anodes for Li-ion batteries to verify its applicability. As shown below, the nanospheres demonstrated excellent Li<sup>+</sup> storage properties over extended (de)lithiation cycling and exhibited high rate capabilities.

## 2. Experimental

### 2.1 Materials synthesis

All the reagents were of analytical grade and used without further purification. The Cu-Sn precursor powder was synthesized by electro-less deposition. The synthesis procedure of Cu-Sn@C nanospheres can be schematically illustrated in Scheme 1 and include three main steps: (i) the electro-less deposition of Sn on Cu nanoparticles, (ii) the polymerization of AN molecules on Cu@Sn surface to obtain Cu@Sn@PANI precursors, and (iii) the formation of Cu-Sn alloy cores and the carbonization of PANI shells *via* heating at 300 °C in an inert atmosphere.

In a typical synthesis, the plating solution was prepared using reagent grade chemicals containing stannous sulfate for as a source of Sn<sup>2+</sup> ions (SnSO<sub>4</sub> 0.32 g L<sup>-1</sup>), citric acid for buffering the solution, sulphuric acid for pH adjustment to pH = 1.0, which was monitored by pH meter (Shanghai Jingke, PHS-3C). Thiourea (100 g L<sup>-1</sup>) was added as a complexing agent to



Scheme 1 Schematic of the preparation of the core-shell Cu<sub>6</sub>Sn<sub>5</sub>@C nanospheres.

form soluble [Cu(NH<sub>2</sub>CSNH<sub>2</sub>)<sub>4</sub>]<sup>2+</sup> ions. First, Cu powder (20 nm, purity 99.99%, Suzhou Canfuo Nanotechnology Company) was cleaned using dilute hydrochloric acid (1%) and acetone before the coating process. Then, the pretreated Cu powder was slowly added to the plating solution under vigorous stirring. Plating was performed for 10 min at 20 °C. After plating, 0.5 mL of aniline (AN) solution (2 mol L<sup>-1</sup>) was added drop-wise to the Sn/Cu suspension. The solution immediately became grey/green in colour when slowly adding the a few drops of H<sub>2</sub>O<sub>2</sub> (2 wt%), indicating the formation of PANI. The residual Cu<sup>2+</sup> in the solution was analyzed by ICP-MS (PerkinElmer Elan DRC-e spectrometer). The powder product was dried under vacuum (10<sup>-5</sup> Pa) at room temperature and heated under nitrogen (to avoid the oxidation of the Cu and Sn metals) to 300 °C at a heating rate of 5 °C min<sup>-1</sup> for 10 h to form the final Cu<sub>6</sub>Sn<sub>5</sub>@C product. Additional Cu-Sn@C composites with different Cu to Sn ratios were prepared for comparison. Expect for the (NH<sub>2</sub>)<sub>2</sub>SC and SnSO<sub>4</sub> concentrations, the synthesis procedures used for these additional samples were the same as those previously described.

### 2.2 Materials characterization

The structures and morphology of the samples were characterized by X-ray diffraction (XRD) (PANalytical X'Pert Pro with Cu K $\alpha$  radiation,  $\lambda = 1.5418$  Å, using a scan rate of 0.03° min<sup>-1</sup>), scanning electronic microscope (SEM, Hitachi S-4700 operated at 15 kV) and transmission electronic microscopy (TEM, Tecnai G2 F30 S-Twin operated at 300 kV). The carbon contents of Cu<sub>6</sub>Sn<sub>5</sub>@C materials were measured using a ThermoFisher Flash EA 1112 analyzer. Fourier transform infrared spectroscopy (FTIR) analysis of Cu@Sn@PANI nanospheres was performed using a Nicolet 6700 spectrometer. Thermogravimetric analysis (TGA) of Cu@Sn@PANI and Cu<sub>6</sub>Sn<sub>5</sub>@C nanospheres was performed with a Perkin Elmer thermobalance at a heating rate of 5 °C min<sup>-1</sup> in a 50 mL min<sup>-1</sup> flow of argon and in air,



respectively. Raman spectra were measured in a back scattering configuration using a micro-Raman spectrometer HR 800 (Jobin Yvon Horiba).

### 2.3 Electrochemical measurements

For electrochemical characterization, electrodes were prepared by mixing 80 wt% of active materials, 10 wt% of acetylene black (Changzhou dafu), and 10 wt% of polyvinylidene fluoride (PVdF) (Shanghai Sanaifu) in a 1-methyl-2-pyrrolidinone (NMP) solution (Shenzhen Huachang). The as-prepared slurry was coated onto a Cu foil and dried at 80 °C for 10 h under vacuum ( $10^{-5}$  Pa). The average loading mass of the electrodes was 1.0–1.1 mg cm $^{-2}$ . Electrochemical cells used Li metal sheet as the counter electrode. The electrolyte was 1 mol dm $^{-3}$  LiPF $_6$  in ethylene carbonate (EC), dimethyl carbonate (DMC), ethylmethyl carbonate (EMC) (1 : 1 : 1, v/v/v) (from Zhangjiagang GuotaiRonghua). Cycling tests were performed at 298 K with various charge–discharge current densities between 0.01–1.2 V and with a LAND CT2001A battery tester. Except noted, the presented capacities are calculated on the basis of the total weight of composites. Cyclic voltammetry (CV) was performed with a Solartron 1287A potentiostat/galvanostat and 1260A impedance/gain-phase analyzer at a scan rate of 0.1 mV s $^{-1}$ . Electrochemical impedance spectra (EIS) were performed on a CHI 660B electrochemical workstation and recorded over a frequency range from  $10^{-2}$  to  $10^5$  Hz, with voltage amplitude of 5 mV at room temperature.

## 3. Results and discussion

### 3.1 Synthesis mechanism, compositions, and performances of Cu–Sn@C nanocomposites

The formation mechanism of Sn shell on Cu nanoparticles by the electro-less deposition can be described as follows:  $(\text{NH}_2)_2\text{SC}$  forms stable complexes with  $\text{Cu}^{2+}$ , e.g.  $[\text{Cu}(\text{NH}_2\text{CSNH}_2)_4]^{2+}/\text{Cu}$  and so by its addition one would expect the electrochemical potential of  $[\text{Cu}(\text{NH}_2\text{CSNH}_2)_4]^{2+}/\text{Cu}$  to move to a more negative value (e.g.  $-0.157$  V when the concentration of  $(\text{NH}_2)_2\text{SC}$  is 1 mol L $^{-1}$ ).<sup>48</sup> Thus some Cu on the surface was replaced by  $\text{Sn}^{2+}$  with the addition of  $(\text{NH}_2)_2\text{SC}$  ( $\text{Cu}^{2+}/\text{Cu}$  and  $\text{Sn}^{2+}/\text{Sn}$  is 0.337 V and  $-0.136$  V, respectively). The electro-less deposition process was initiated. The solvated  $\text{Cu}^{2+}$  would return to the Cu particle by combining the  $\text{Sn}^{2+}$  (to form  $\text{Cu}_6\text{Sn}_5$ ), and the residual  $\text{Cu}^{2+}$  concentration was found to be as low as 0.0001 mol L $^{-1}$  after synthesis indicating that the previously replaced  $\text{Cu}^{2+}$  could be deposited to the Cu particles. Afterwards, Sn started to be deposited to form Sn layer around Cu particles.

The concentrations of  $(\text{NH}_2)_2\text{SC}$  and  $\text{SnSO}_4$  were modified in an effort to exert a greater control over the final compositions of the Cu–Sn@C materials. Table 1 summarizes the effect of the preparation conditions on the phase properties for the obtained products (according to XRD analysis as shown in Fig. S1†). Diffraction data show that the concentrations of  $(\text{NH}_2)_2\text{SC}$  and  $\text{Sn}^{2+}$  greatly affect the final phase composition due to different Cu : Sn ratios resulting from the electro-less reduction. For

instance, when the concentration of  $(\text{NH}_2)_2\text{SC}$  is lower than 100 g L $^{-1}$  and the concentration of  $\text{Sn}^{2+}$  fixes at 0.1 mol L $^{-1}$ , metallic copper and other Cu-rich phases (e.g.  $\text{Cu}_3\text{Sn}$ ) are found in the final product (samples a–d). The occurrence of these phases can be ascribed to the relatively small quantity of Sn plated in the Cu@Sn@PANI precursors. By increasing the concentration of  $\text{Sn}^{2+}$  ions, the Cu and  $\text{Cu}_3\text{Sn}$  phases are gradually removed and the reflections from  $\text{Cu}_6\text{Sn}_5$  become dominant (samples d–f). The Cu : Sn mole ratio of sample f is 5.9 : 5.1 confirmed by EDX. Inevitably, a high concentration of  $\text{Sn}^{2+}$  ions resulted in a large amount of Sn in the product (e.g. sample g).

Table 2 summarizes the electrochemical performances of Cu–Sn@C nanospheres (samples a–g). Cu-Rich samples (e.g. a–e) exhibit an extended reversible capacity of  $<370$  mA h g $^{-1}$  after 100 cycles. For Sn-rich samples (e.g. sample g), however, the capacity fading over 100 cycles is significant although the initial capacity is high, presumably due to presence of unprotected Sn. Given that the sample f is with the best electrochemical properties, we therefore devoted our efforts to this sample to study its electrochemical properties in detail.

### 3.2 Materials characterization of core–shell $\text{Cu}_6\text{Sn}_5$ @C

The electro-less deposition of  $\text{Sn}^{2+}$  ions and polymerization of AN were conducted in sequence on Cu nanoparticles to fabricate the Cu@Sn@PANI precursors. The phase composition of the starting and intermediate compounds for sample f was determined by XRD and the results are shown in Fig. 1. All the reflections of the Cu nanoparticles could be readily indexed to cubic Cu (JCPDS no. 01-1241). Reflections in the XRD pattern of Cu@Sn@PANI could also be attributed to Cu, with additional reflections that could be assigned to Sn (JCPDS no. 04-0673), implying that a Cu–Sn composite was formed. Note that, due to the high surface energy of the Cu nanoparticles, some of the deposited Sn at Cu/Sn interface would also readily diffuse into the Cu lattice to form  $\text{Cu}_6\text{Sn}_5$ , which appears in the Cu@Sn@PANI nanospheres. XRD patterns of the  $\text{Cu}_6\text{Sn}_5$ @C nanospheres obtained after heat treatment were indexed to monoclinic  $\text{Cu}_6\text{Sn}_5$  ( $C2/c$ , JCPDS no. 45-1488) with an average crystalline size of  $\sim 40$  nm, (using the Scherrer equation:  $D = K\lambda/\beta \cos \theta$ ). The absence of a diffraction reflection at  $2\theta = 23^\circ$  indicates that carbon resulting from the PANI decomposition may exist in an amorphous form.

The formation of PANI in the Cu@Sn@PANI precursors can be observed *via* FTIR analysis as shown in Fig. 2a. The absorption bands at 1548 and 1497 cm $^{-1}$  are assigned to C=C stretching deformation of the quinoid and benzoid rings of PANI, respectively. The bands at 1300 cm $^{-1}$  belongs to the C–N stretching of the intermediate aromatic amine, while the bonds at 1136 and 814 cm $^{-1}$  correspond to the C–H deformations. After heat treatment, the characteristic peaks of PANI disappear as would be expected as PANI decomposes into carbon. TGA (Fig. 2b) in flow argon of Cu@Sn@PANI shows that the removal of adsorbed water and the carbonization process mainly occur before 300 °C and lead to a mass loss of 10.5 wt%. This observation can explain why we adopt 300 °C as the annealing



**Table 1** Summary of phases and elemental compositions of Cu–Sn@C samples prepared under different electro-less reduction conditions

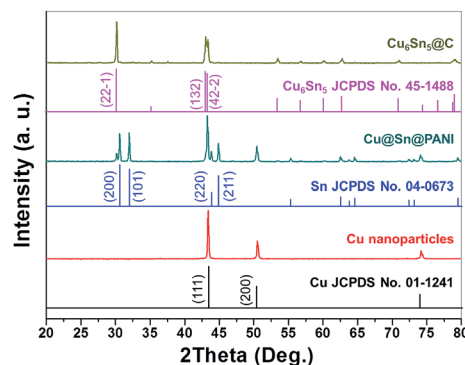
Samples	$C_{(NH_2)_2SC}^a$	$C_{SnSO_4}^b$	Cu	Sn	$Cu_3Sn$	$Cu_6Sn_5$	Mole ratio of Cu : Sn by EDX
Sample a	40	0.15	●		●		6.3 : 0.7
Sample b	80	0.15	●		●	●	3.3 : 1.1
Sample c	100	0.15	●	●	●	●	2.1 : 0.9
Sample d	120	0.15	●	●	●	●	2.9 : 1.1
Sample e	100	0.25			●	●	3.1 : 2.2
Sample f	100	0.32				●	5.9 : 5.1
Sample g	100	0.50		●		●	6.1 : 7.4

<sup>a</sup> Concentrations of  $(NH_2)_2SC$ , g L<sup>-1</sup>. <sup>b</sup> Concentrations of  $SnSO_4$ , g L<sup>-1</sup>.

temperature, as higher temperatures trend to result in agglomeration of alloy nanoparticles.

After heat treatment, the PANI converted into amorphous carbon confirmed by Raman spectroscopy, as shown in Fig. 2c, which is recognized as predictive for sp<sup>2</sup> bonded carbons and physical properties of carbon materials. The strong bands at 1340 and 1590 cm<sup>-1</sup> are respectively attributed to the D-band and G-band of carbon.<sup>49</sup> The  $I_D/I_G$  ratio is calculated to be 1.59, implying that the carbon obtained from the carbonization of PANI is almost amorphous. Fig. 2d shows TGA curve for  $Cu_6Sn_5$ @C nanospheres in air. The mass loss of ~2 wt% before 200 °C can be mainly ascribed to the releasing of absorbed water, while the loss of ~3 wt% at 200–380 °C belongs to the preliminary oxidation of carbon coating. However, the complete removal of carbon generally happens in the temperature range of 400–500 °C, where a significant mass increasing of over 10 wt% appears due to the surface oxidation of  $Cu_6Sn_5$ . Therefore, it is inaccurate to estimate the detail carbon content. Elemental analysis was conducted instead and showed the carbon content was 9.8 wt%.

TEM images of the  $Cu@Sn@PANI$  and  $Cu_6Sn_5$ @C nanospheres are shown in Fig. 3. The average size of the  $Cu_6Sn_5$ @C nanoparticles are in the range of 40–50 nm, in good agreement with the values calculated from XRD patterns and SEM image (Fig. S2†). The sizes of the  $Cu_6Sn_5$ @C nanoparticles are almost identical to those of the  $Cu@Sn@PANI$  intermediate (Fig. 3a and b). This observation indicates that the PANI layer can effectively prevent agglomeration during the melting and alloying of Sn with Cu to make Cu–Sn intermetallic phases while maintaining the

**Fig. 1** XRD patterns of Cu nanoparticles,  $Cu@Sn@PANI$  precursors, and core-shell  $Cu_6Sn_5$ @C nanospheres.

nanoscale morphology of the composite. The transformation from  $Cu@Sn@PANI$  to  $Cu_6Sn_5$ @C is thus essentially pseudomorphic. A TEM image of a selected  $Cu_6Sn_5$ @C particle clearly reveals that a coarse carbon layer forms around the core particle (Fig. 3c), where the carbon layer originates from the decomposition of the previously deposited PANI shell. It also demonstrates that the thickness of the carbon layer is ca. 5 nm. Selected area electron diffraction (SAED) patterns further confirms the crystalline nature of the core material and could be indexed to the monoclinic  $Cu_6Sn_5$ . At high resolution, TEM image (Fig. 3d) shows that the distance between neighboring fringes is 2.1 Å, very close to the (132) *d*-spacing in the monoclinic structure of  $Cu_6Sn_5$ . Therefore,

**Table 2** Summary of electrochemical properties of Cu–Sn@C samples synthesized under different preparation conditions

Samples	Initial DC <sup>a</sup>	100 <sup>th</sup> DC	Cycling retention	CC <sup>b</sup> at 1C	CC at 2C	CC at 5C
Sample a	113	105	92.9%	87	73	69
Sample b	138	118	85.5%	104	81	75
Sample c	220	179	81.4%	137	94	82
Sample d	361	273	75.6%	217	138	91
Sample e	510	369	72.4%	251	143	91
Sample f	686	490	71.4%	334	275	206
Sample g	828	405	48.9%	175	118	101

<sup>a</sup> Discharge capacity. <sup>b</sup> Charge capacity.





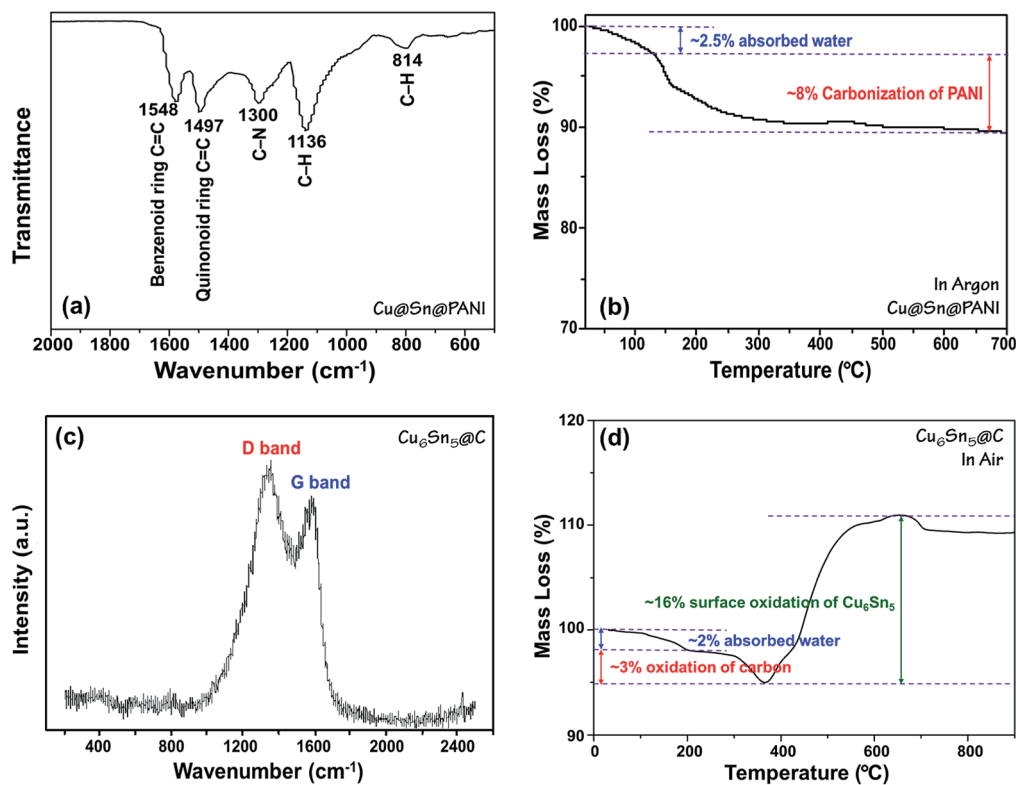


Fig. 2 (a) FTIR spectrum and (b) TGA curve in Ar of Cu@Sn@PANI precursors; (c) Raman spectrum and (d) TGA curve in air of Cu<sub>6</sub>Sn<sub>5</sub>@C nanospheres.

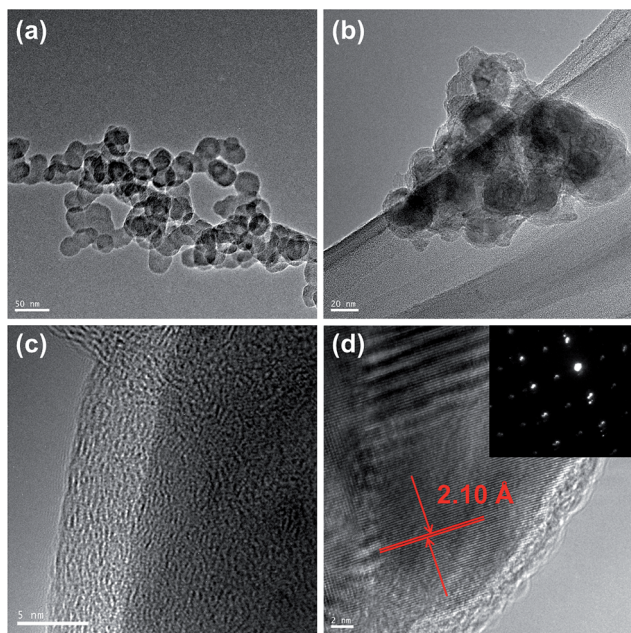
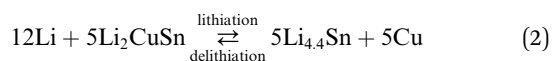
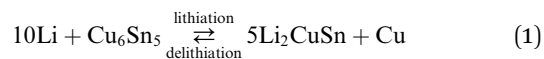


Fig. 3 TEM images of (a) Cu@Sn@PANI precursors and (b) resultant Cu<sub>6</sub>Sn<sub>5</sub>@C nanospheres. (c) HRTEM image and (d) SAED patterns of Cu<sub>6</sub>Sn<sub>5</sub>@C. Scale bars are 50, 20, 5, and 2 nm separately.

based on all the results discussed above, it can be deduced that core-shell Cu<sub>6</sub>Sn<sub>5</sub>@C nanospheres were successfully prepared from Cu@Sn@PANI precursors.

### 3.3 Electrochemical performances of core-shell Cu<sub>6</sub>Sn<sub>5</sub>@C nanospheres

The core-shell Cu<sub>6</sub>Sn<sub>5</sub>@C nanospheres were electrochemically characterized by CV, charge-discharge profiles, and cycling performances at different rates in CR-2032 coin cells (shown in Fig. 4). CV curves for the Cu<sub>6</sub>Sn<sub>5</sub>@C sample are shown in Fig. 4a. Over the course of the lithiation process the CV profiles show two apparent reduction peaks at *ca.* 0.35 and 0.55 V, corresponding to the formation of Li<sub>2</sub>CuSn and Li<sub>4.4</sub>Sn as shown in eqn (1) and (2), respectively. In contrast to previous studies, irreversible peaks at potentials above 1.0 V due to catalytic decomposition of the electrolyte on the exposed active Sn surface were not observed in our data.<sup>50</sup> The absence of these features at higher potential could be ascribed to the protection of the Cu<sub>6</sub>Sn<sub>5</sub> core by the carbon shell, which inhibits such side reactions.



Typical charge-discharge voltage curves of the Cu<sub>6</sub>Sn<sub>5</sub>@C nanospheres cycled between 0.01 and 1.20 V were given in Fig. 4b. Several different potential regions can be identified in the discharge profiles between 0.4 and 0.1 V. In the first cycle, the discharging and charging capacity were 914.2 and 815 mA h



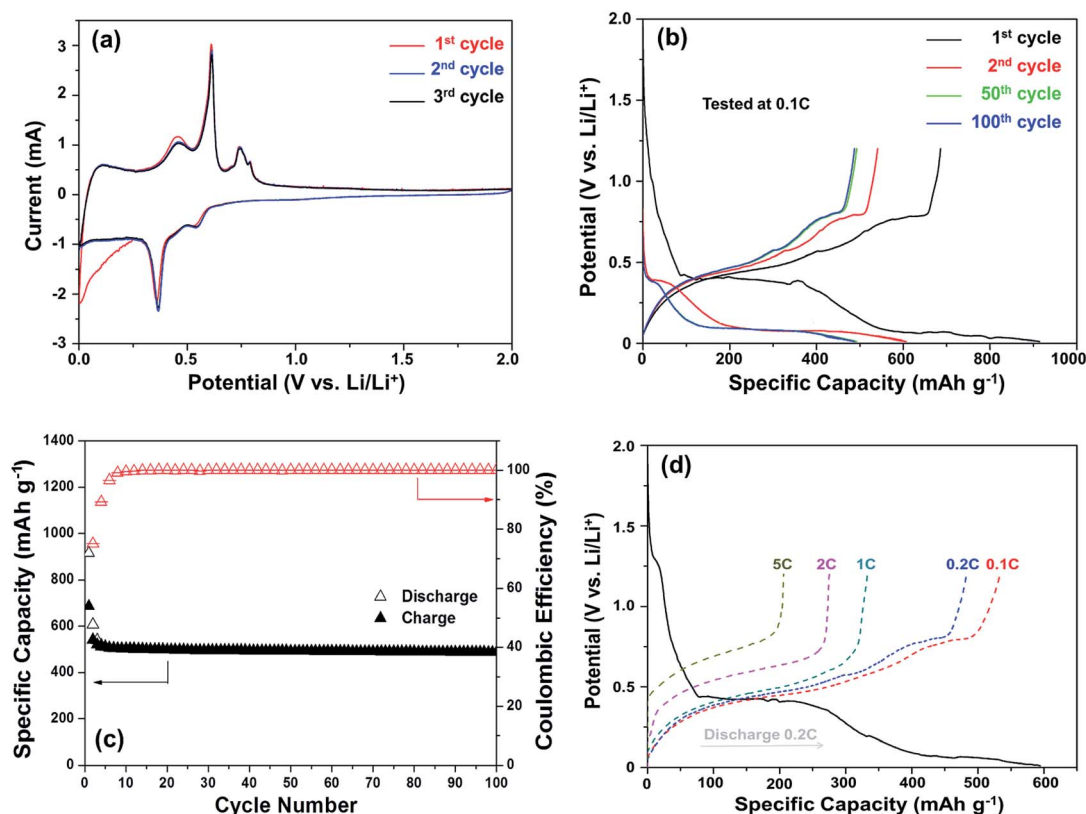


Fig. 4 Electrochemical performances of Li/Cu<sub>6</sub>Sn<sub>5</sub>@C cells: (a) CV curves at a scan rate of 0.1 mV s<sup>-1</sup>, (b) charge/discharge profiles at 0.1C (1C = 605 mA g<sup>-1</sup>), (c) the cycleability and coulombic efficiency at 0.1C, and (d) high-rate performances.

g<sup>-1</sup>, respectively, resulting in a coulombic efficiency of 89.2%. The irreversible capacity observed in the first cycle can be attributed to the formation of a solid electrolyte interface (SEI) film. The level of SEI formation is proportional to the surface area and the quality of coating, and a homogeneous carbon coating would effectively suppress the formation of coarse SEI layer. The initial coulombic efficiency (ICE) of the Cu<sub>6</sub>Sn<sub>5</sub>@C nanospheres is 89.2% higher than the uncoated nanosized Cu-Sn anode materials (usually less than 75%, see details in Table

3). In the following cycles, Cu<sub>6</sub>Sn<sub>5</sub>@C demonstrates a coulombic efficiency of more than 99%. The charge-discharge profiles are in accord with the CV results and the close overlap of the curves offer further evidence for the observed high coulombic efficiency.

The cycling performance of the Cu<sub>6</sub>Sn<sub>5</sub>@C nanospheres is shown in Fig. 4c. It shows a ability of maintaining a reversible capacity of 518 mA h g<sup>-1</sup> without significant fading after an initial decrease in the first few cycles. If excluding the

Table 3 Summary of lithium storage performances between core-shell Cu<sub>6</sub>Sn<sub>5</sub>@C nanospheres herein and representative Cu<sub>6</sub>Sn<sub>5</sub>-based materials reported previously

Materials	Carbon (%)	RC (mA h g <sup>-1</sup> )	ICE <sup>c</sup> (%)	Current (mA g <sup>-1</sup> )	Cycles	Ref.
Porous Cu <sub>6</sub> Sn <sub>5</sub>	0	404	73	100	100	38
Porous Cu <sub>6</sub> Sn <sub>5</sub>	0	420	83 <sup>b</sup>	0.5 mA cm <sup>-2</sup>	20	21
Microporous Cu <sub>6</sub> Sn <sub>5</sub> -Sn	0	400	58	666	54	51
Cu <sub>6</sub> Sn <sub>5</sub> /carbon fiber	— <sup>a</sup>	250	68	131	30	37
Cu <sub>6</sub> Sn <sub>5</sub> @C on carbon	53.7	366	56.5	1000	200	18
Cu <sub>6</sub> Sn <sub>5</sub> /C	8.86	400	—	140 <sup>b</sup>	100	52
Cu <sub>6</sub> Sn <sub>5</sub> /GNS	52.6 <sup>b</sup>	411	70	500	1600	20
Sn rich Cu <sub>6</sub> Sn <sub>5</sub>	0	440	98	200	50	53
Cu <sub>6</sub> Sn <sub>5</sub> @SnO <sub>2</sub> -C	— <sup>a</sup>	619	65	200	500	54
Cu <sub>6</sub> Sn <sub>5</sub> nanoparticles	0	490	71.4	60	100	This work
Core-shell Cu <sub>6</sub> Sn <sub>5</sub> @C	9.8	518	89.2	60	100	This work

<sup>a</sup> Not given in references. <sup>b</sup> Calculated according to the given data. <sup>c</sup> ICE: initial coulombic efficiency.



contribution of 9.8 wt% carbon, the exact capacity of Cu<sub>6</sub>Sn<sub>5</sub> cores is *ca.* 570 mA h g<sup>-1</sup>, that is very close to its theoretical value of 605 mA h g<sup>-1</sup> calculated according to eqn (1) and (2). Rate capability is an important factor in evaluating the potential application of anode materials. This motivated us to investigate the rate performance of the Cu<sub>6</sub>Sn<sub>5</sub>@C nanospheres further. Fig. 4d displays the rate capability of the Cu<sub>6</sub>Sn<sub>5</sub>@C nanospheres at rates of 0.1–5C. The Cu<sub>6</sub>Sn<sub>5</sub>@C nanospheres maintain a steady capacity output at high current densities, *e.g.* 488 mA h g<sup>-1</sup> at 0.2C, 331 mA h g<sup>-1</sup> at 1C, 275 mA h g<sup>-1</sup> at 2C, and 206 mA h g<sup>-1</sup> at 5C. Fig. S3† demonstrates that the Cu<sub>6</sub>Sn<sub>5</sub>@C nanospheres still maintain a structural integrity and a reversible crystalline phase of Cu<sub>6</sub>Sn<sub>5</sub> after 30 cycles at 0.2C.

Table 3 compares the lithium storage performance of the core-shell Cu<sub>6</sub>Sn<sub>5</sub>@C nanospheres with representative Cu<sub>6</sub>Sn<sub>5</sub>-based materials reported previously. Totally speaking, the core-shell Cu<sub>6</sub>Sn<sub>5</sub>@C nanospheres in this work exhibit comparable or even better performance especially at a relatively low rate. To the best of our knowledge, both the reversible capacity of 518 mA h g<sup>-1</sup> and the initial coulombic efficiency of 89.2% are the highest value in pure Cu<sub>6</sub>Sn<sub>5</sub> and Cu<sub>6</sub>Sn<sub>5</sub>/C materials. Note that, with the help of high-capacity materials such as Sn<sup>53</sup> and SnO<sub>2</sub>,<sup>54</sup> the counterpart performance can be further enhanced. The impressive performance can be ascribed to the reduced Li<sup>+</sup> ion diffusion pathways in the nanoscale material and the enhanced conductivity imparted by the carbon shell.

## 4. Conclusions

In conclusion, a controllable electro-less reduction strategy was reported to prepare uniform core-shell Cu<sub>6</sub>Sn<sub>5</sub>@C nanospheres from Cu@Sn@PANI precursors. The composition and lithium storage performance of the Cu-Sn@C nanospheres were heavily influenced by the synthesis parameters. Isolated, approximately isotropic Cu<sub>6</sub>Sn<sub>5</sub>/C nanospheres (40–50 nm in diameter) exhibited a demonstrably superior electrochemical performance to those composites prepared with alternative Sn : Cu ratios and offers promise as a candidate high power anode material.

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